National Semiconductor

LM382 Low Noise Dual Preamplifier

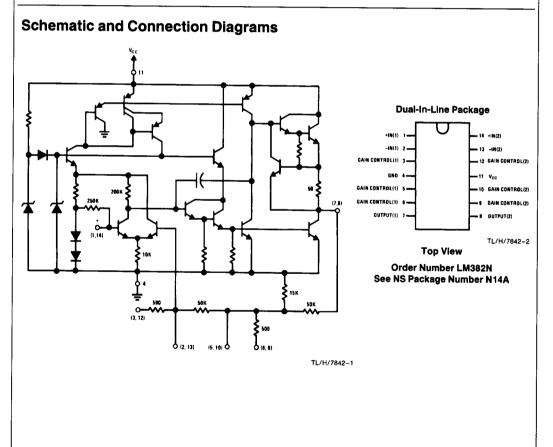
General Description

The LM382 is a dual preamplifier for the amplification of low level signals in applications requiring optimum noise performance. Each of the two amplifiers is completely independent, with individual internal power supply decoupler-regulator, providing 120 dB supply rejection and 60 dB channel separation. Other outstanding features include high gain (100 dB), and wide power bandwidth (75 kHz, 20 Vp-p). The LM382 operates from a single supply across the wide range of 9V to 40V.

A resistor matrix is provided on the chip to allow the user to select a variety of closed loop gain options and frequency response characteristics such as flat-band, NAB or RIAA equalization. The circuit is supplied in the 14 lead dual-inline package.

Features

- Low noise --- 0.8 µV total equivalent input noise
- High gain 100 dB open loop
- Single supply operation
- Wide supply range 9V to 40V
- Power supply rejection 120 dB
- Large output voltage swing
- Wide bandwidth 15 MHz unity gain
- Power bandwidth 75 kHz, 20 Vp-p
- Internally compensated
- Short circuit protected



Absolute Maximum Ratings If Military/Aerospace specified devices are required,

please contact the National Semiconductor Sales Office/Distributors for availability and specifications. + 40V **Operating Temperature Range** Storage Temperature Range Lead Temperature (Soldering, 10 sec.)

0°C to + 70°C -65°C to +150°C +260°C LM382

Power Dissipation (Note 1)

Supply Voltage

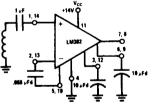
Electrica	Characteristic	S T _A = 25°C, V _{CC} =	14V, unless otherwise stated.
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1.56 W

Parameter	Conditions	Min	Тур	Max	Units
Voltage Gain	Open Loop, f = 100 Hz		100,000		V/V
Supply Current	V_{CC} 9V to 40V, $R_L = \infty$		10	20	mA
Output DC Voltage			6		V
Input Resistance (Positive Input)			100		kΩ
(Negative Input)			200		kΩ
Input Current (Negative Input)			0.5		μA
Output Resistance	Open Loop		150		Ω
Output Current	Source		8		mA
	Sink		2		mA
Output Voltage Swing	Peak-to-Peak, RL = 10k		12		v
Unity Gain Bandwidth			15		MHz
Power Bandwidth	20 Vp-p (V _{CC} = 24V)		75		kHz
Maximum Input Voltage	Linear Operation			300	mVrm
Supply Rejection Ratio	f = 1 kHz		120		dB
Channel Separation	f = 1 kHz	40	60		dB
Total Harmonic Distortion	60 dB Gain, f = 1 kHz		0.1	0.3	%
Total Equivalent Input Noise	$R_S = 600\Omega$, 100–10,000 Hz (Flat Response Circuit)		0.8	1.2	μVrm

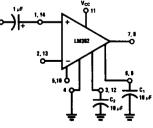
Note 1: For operation in ambient temperatures above 25°C, the device must be derated based on a 150°C maximum junction temperature and a thermal resistance of 80°C/W junction to ambient.

Typical Applications



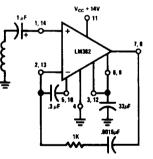
TL/H/7842-3

Tape Preamp (NAB Equalization)



TL/H/7842-5

Flat Response — Fixed Gain Configuration



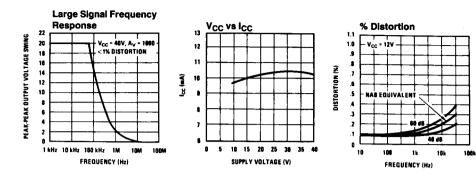
TL/H/7842-4

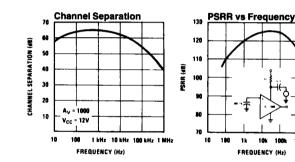
Phono Preamp (RIAA Equalization)

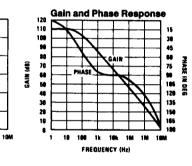
Capacitor	Gain	
C1 Only	40 dB	
C2 Only	55 dB	
C1 & C2	80 dB	

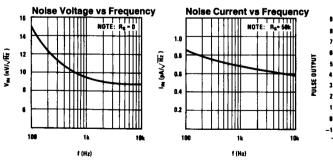
Typical Performance Characteristics

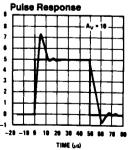
LM382











TL/H/7842-6

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1006 1M This datasheet has been downloaded from:

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Datasheets for electronic components.

National Semiconductor was acquired by Texas Instruments.

http://www.ti.com/corp/docs/investor_relations/pr_09_23_2011_national_semiconductor.html

This file is the datasheet for the following electronic components:

LM382 - http://www.ti.com/product/Im382?HQS=TI-null-null-dscatalog-df-pf-null-wwe